

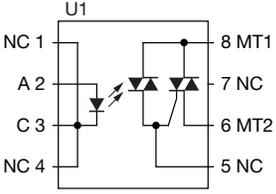
Power Phototriac Optocoupler VO2223

DESCRIPTION

This device is an optically coupled phototriac driving an integrated power TRIAC in a DIP-8 package. The PSpice models have been written from device characterization data and were tested with simulation program OrCAD16.6.

The symbol and model files as well as the netlist are in the symbol library file VO2223B.olb, model library file VO2223B.lib, and netlist file VO2223B.txt respectively for this model.

This document is intended as a guideline of simulating with provided model and does not constitute as commercial product, neither a substitute to datasheet.

PART	MODEL DESCRIPTION	SYMBOL FILE	MODEL FILE
VO2223B	Power phototriac	 VO2223B VO2223B.olb	VO2223B.lib

RECOMMENDED USE OF THE MODEL

- This model is designed only for use at 25 °C and should be used as is
- This model has been created and tested with OrCAD version 16.6
- The olb file (symbol) is not down-compatible. Users of the earlier versions need to create the symbols on their platform and associate with relative PSpice model data

NETLIST OF MODEL

Following list shows the netlist of the model:

- * Library of Power Phototriac Optocoupler VO2223B
- * Copyright VISHAY, Inc. 2018 All Rights Reserved.

```
.SUBCKT VO2223B NC C A NC MT1 NC MT2 NC
X1      MT1 GATE MT2 VO2223B_tr
D1      10 C Demit
V3      11 10 0Vdc ; emitter current probe
R3      A 11 1u TC=0,0
R4      0 NC 1MEG
C1      0 NC 1u
G1      0 GATE VALUE { I(v3) * 0.6 }
.MODEL Demit d
+IS=5.60248e-15 RS=1.43261 N=1.58216 EG=1.3
+XTI=3.75582 BV=1 IBV=5e-6 CJO=1e-11
+VJ=0.7 M=0.5 FC=0.5 TT=1e-09
+KF=0 AF=1
.ENDS
*****
```



```
.SUBCKT VO2223B_tr 3 2 1
*   TERMINALS: MT1 G MT2
QN1 5 4 3 NOUT OFF
QN2 11 6 7 NOUT OFF
QP1 6 11 3 POUT OFF
QP2 4 5 7 POUT OFF
DF 4 5 DZ
DR 6 11 DZ
RF 4 6 60.0G
RT2 1 7 0.45
RH 7 6 18.75k
RGP 8 3 102
RG 2 8 998
RS 8 4 3.65k
DN 9 2 DIN
RN 9 3 855
GNN 6 7 9 3 24.3u
GNP 4 5 9 3 26.5u
DP 2 10 DIP
RP 10 3 110k
GP 7 6 10 3 20.5u
.MODEL DIP D ( IS=1.07f N=1.50 )
.MODEL DIN D ( IS=1.07f )
.MODEL DZ D ( IS=1.07f N=1.5 IBV=10.0n BV=600 )
.MODEL POUT PNP ( IS=1.07f BF=5 BR=.1 CJE=35f TF=1.8u )
.MODEL NOUT NPN ( IS=1.07f BF=20 BR=.1 CJE=35f CJC=67.0f TF=1.080u )
.ENDS
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* Note:

* Although models can be a useful tool in evaluating device performance, they cannot model exact device performance under all conditions, nor are they intended to replace breadboarding for final verification!

* Models provided by VISHAY Semiconductors GmbH are not as fully representing all of the specifications and operating characteristics of the semiconductor product to which the model relates.

* The models describe the characteristics of typical devices.

* In all cases, the current data sheet information for a given device is the final design guideline and the only actual performance specification.

* VISHAY Semiconductors does not assume any liability arising from the model use. VISHAY Semiconductors reserves the right to change models without prior notice.

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SIMULATED PARAMETERS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	SIMULATION DATA	UNIT
INPUT				
Forward voltage	$I_F = 10\text{ mA}$	V_F	1.21	V
Trigger input current	$V_T = 6\text{ V}$	I_{FT}	4.8	mA
OUTPUT				
Repetitive peak off-state voltage		V_{DRM}	600	V

EXAMPLE SIMULATION PLOTS USING OrCAD

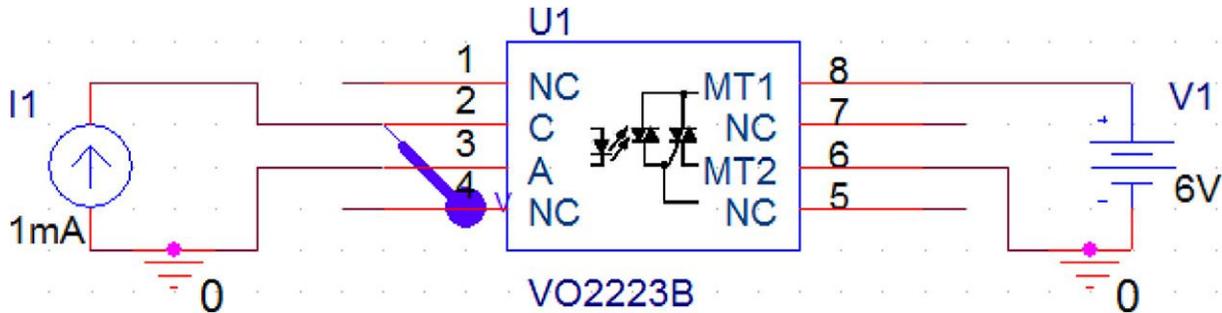


Fig. 1 - Simulation Setup for V_F vs. I_F Curve

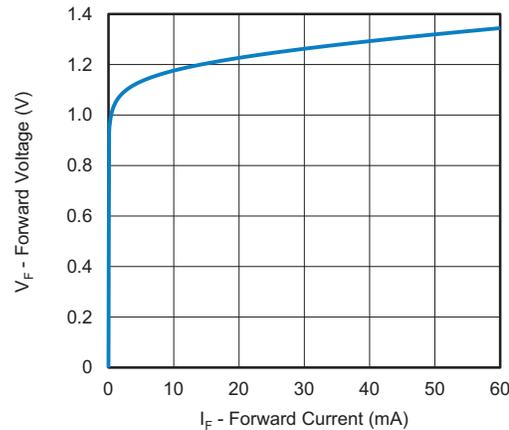


Fig. 2 - Forward Current vs. Forward Voltage

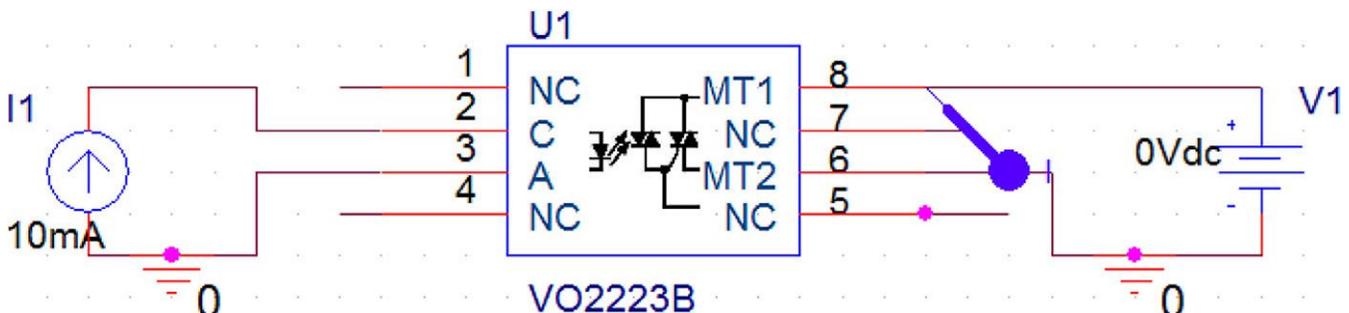


Fig. 3 - Simulation Setup for V_{TM} Curve

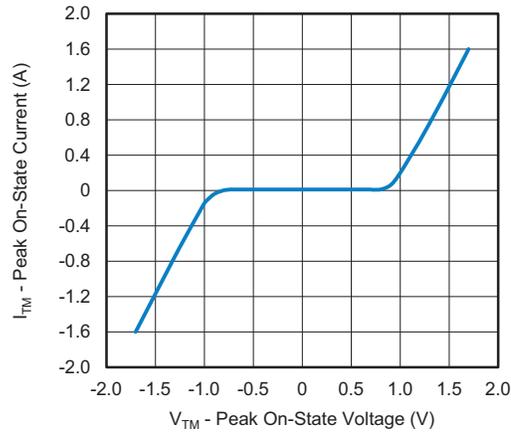


Fig. 4 - On-State Current vs. On-State Voltage